



PATENT

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant(s): Xuming Xiong, et al.

Title: BLAXIALLY-TEXTURED FILM DEPOSITION FOR  
SUPERCONDUCTOR COATED TAPES

Application No.: 10/821,010

Filed: April 8, 2004

Examiner: UNASSIGNED

Group Art Unit: 1775

Atty. Docket No.: 1014-SP215

COMMISSIONER FOR PATENTS  
PO Box 1450  
Alexandria, VA 22313-1450

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Dear Sir:

Pursuant to 37 C.F.R. § 1.56, § 1.97 and § 1.98, the undersigned brings the patents, publications, applications or other information identified in the attached:

- ☒ Form(s) PTO/SB/08A and/or PTO/SB/08B or PTO/1449  
☐ Other: n/a

to the Examiner's attention in the above-identified application. Citation of such information shall not be construed as:

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If the above-identified application is an original application filed on or after May 29, 2000:

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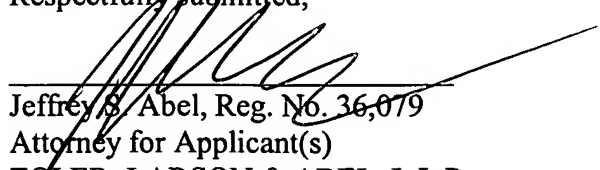
- ☐ within three months of the filing date of a national application or within three months of entry of the national stage as set forth in § 1.491 in an international application. Therefore, no fee is required.
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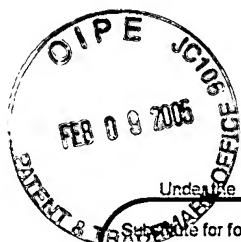
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Date

2/3/05

Respectfully submitted,

  
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PTO/SB/08B (08-03)

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<b>INFORMATION DISCLOSURE STATEMENT BY APPLICANT</b>  (Use as many sheets as necessary)		<b>Complete if Known</b>			
		Application Number	10/821,010		
		Filing Date	April 8, 2004		
		First Named Inventor	Xuming Xiong		
		Art Unit	1775		
		Examiner Name	Unassigned		
Sheet	1	of	1	Attorney Docket Number	1014-SP215-US

NON PATENT LITERATURE DOCUMENTS			
Examiner Initials*	Cite No. <sup>1</sup>	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	T <sup>2</sup>
	A	Y. Iijima, et al., "In-Plane Aligned YBa <sub>2</sub> Cu <sub>3</sub> O <sub>7-x</sub> Thin Films Deposited on Polycrystalline Metallic Substrates", Appl. Phys. Letters, Vol. 60, pp. 769-771, 1992.	
	B	X. Wu, et al., "Properties of YBa <sub>2</sub> Cu <sub>3</sub> O <sub>7-s</sub> Thick Films on Flexible Buffered Metallic Substrates", Appl. Phys. Letters, Vol. 67, No. 16, pp. 2397-2399, 1995.	
	C	H. Freyhardt, et al., "YBaCuO Thick Films on Planar and Curved Technical Substrates", Vol. 7, No. 2, pp. 1426-1431, 1997.	
	D	R. Huehne, et al., "Growth of Biaxial Textured MgO-Layers by Ion-Beam Assisted Pulsed Laser Deposition", Crystal Res. Technology, Vol. 35, No. 4, pp. 419-425, 2000.	
	E	L. Dong, et al., "Texture Development Mechanisms in Ion Beam Assisted Deposition", Journal of Applied Physics, Vol. 84, No. 9, pp. 5261-5269, 1998.	
	F	J. Groves, et al., "Recent Progress in Continuously Processes IBAD MgO Template Meters for HTS Applications, Physica C 382, pp. 43-47, 2002.	
	G		
	H		
	I		
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Examiner Signature	Date Considered
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\*EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

<sup>1</sup> Applicant's unique citation designation number (optional). <sup>2</sup> Applicant is to place a check mark here if English language Translation is attached.

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